

Description

The AO4403 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

 $V_{DS} = -30 V I_D = -5.8 A$

 $R_{DS(ON)} < 55 \, m\Omega @ V_{GS} = 10V$

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

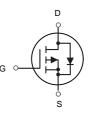
Product ID	Pack	Brand	Qty(PCS)
AO4403	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	- 30	V
VGS	Gate-Source Voltage	±20	V
I _D @T _A =25°C	Drain Current ³ , V _{GS} @ 10V	-5.8	А
IDM	Pulsed Drain Current ¹	-20	А
P _D @T _A =25°C	Total Power Dissipation	2.5	W
	Linear Derating Factor	0.02	W/°C
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
Rthj-a	Maximum Thermal Resistance, Junction-ambient ³	50	°C/W







P-Channel MOSFET



Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			1	I		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	loss	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	lgss	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)			1			
Gate Threshold Voltage	VGS(th)	V _{DS} =V _{GS} ,I _D =-250µA	-1	-1.6	-3	V
	Rds(on)	V _{GS} =-10V, I _D =-5.1A	-	43	55	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4.2A	-	62	90	mΩ
Forward Transconductance	gfs	V _{DS} =-15V,I _D =-4.5A	4	7	-	S
Dynamic Characteristics (Note4)	I.	1			I	
Input Capacitance	Clss		-	520	-	PF
Output Capacitance	Coss	V _{DS} =-15V,V _{GS} =0V,	-	130	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	70	-	PF
Switching Characteristics (Note 4)		L	1		ł	
Turn-on Delay Time	td(on)		-	7	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V, ID=-1A, V _{GS} =-	-	13	-	nS
Turn-Off Delay Time	td(off)	10V,R _{GEN} =6Ω	-	14	-	nS
Turn-Off Fall Time	tr		-	9	-	nS
Total Gate Charge	Qg		-	11	-	nC
Gate-Source Charge	Qgs	V _{DS} =-15V,I _D =-5.1A,V _{GS} =- 10V	-	2.2	-	nC
Gate-Drain Charge	Q _{gd}		-	3	-	nC
Drain-Source Diode Characteristics	1	1	1		I	
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =-5.1A	-	-	-1.2	V

Electrical Characteristics (T_A=25°C unless otherwise noted)

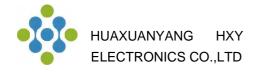
Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

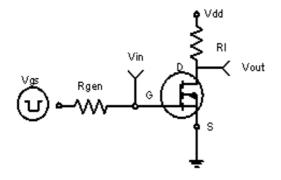


Figure 1:Switching Test Circuit

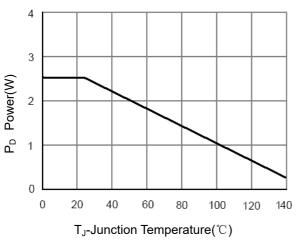
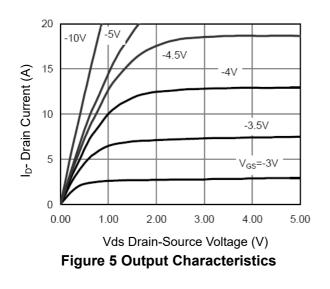


Figure 3 Power Dissipation



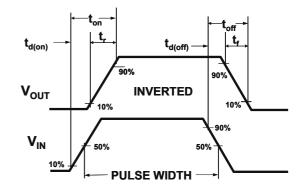
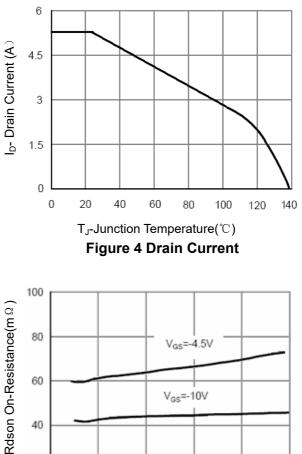


Figure 2:Switching Waveforms



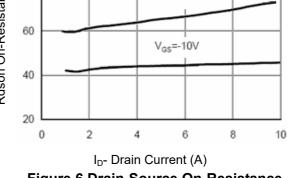
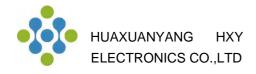


Figure 6 Drain-Source On-Resistance



75

20

25

- 50 °C

 $T_J =$

1.0

1.2

1.4

0.8

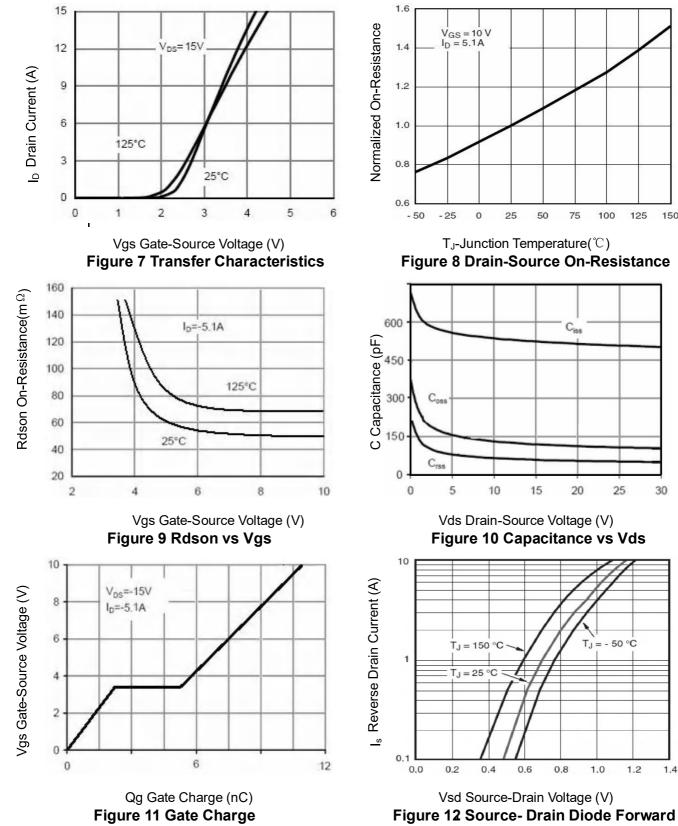
30

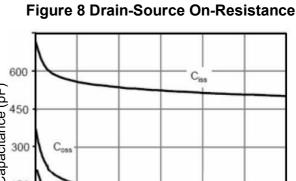
100

125

150

Figure 5 Output Characteristics







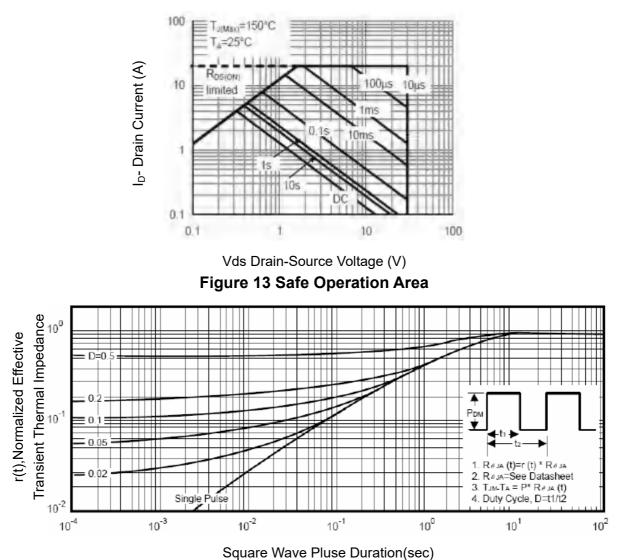
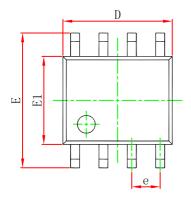
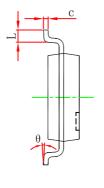


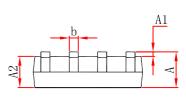
Figure 14 Normalized Maximum Transient Thermal Impedance



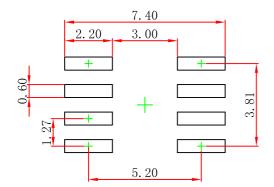
SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0.197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6.200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0 °	8°	0 °	8°	



Note: 1.Controlling dimension: in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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